NSN 5961-01-250-3389

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View Online at https://aerobasegroup.com/nsn/5961-01-250-3389 **Inclosure Material:** Metal **Overall Length:** 0.935 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-60 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.40 amperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:**

Fiig:

No

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Demilitarization: